## NSN 5962-01-304-1983

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View Online at https://aerobasegroup.com/nsn/5962-01-304-1983 **Body Length:** 1.490 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** Between 0.172 inches and 0.217 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and ultraviolet erasable and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 17 input **Case Outline Source And Designator:** 

D-10 mil-m-38510

**Terminal Surface Treatment:** 

Solder

**Voltage Rating And Type Per Characteristic:** 

-0.3 volts power source and 7.0 volts power source

**Time Rating Per Chacteristic:** 

250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level output

**Memory Device Type:** 

Rom

Memory Capacity:

Unknown

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

28 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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## Demilitarization:

Yes - demil/mli

Fiig:

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